



AH3241Q, AH3242Q, AH3243Q AH3280Q, AH3281Q, AH3282Q

TWO-WIRE AUTOMOTIVE HALL EFFECT UNIPOLAR / LATCH SWITCHES INTEGRATED SELF-DIAGNOSTICS

Description

The AH3241Q, AH3242Q, AH3243Q, AH3280Q, AH3281Q, and AH3282Q are high voltage, high sensitivity two-wire Hall Effect Unipolar/Latch switch ICs with integrated self-diagnostics and automotive-compliant AEC-Q100 qualification; designed for position and proximity sensing in automotive applications, such as seat and seatbelt buckle, transmission actuator, gear position, wiper, door/trunk closure, etc.

To support a wide range of demanding applications, the AH3241Q, AH3242Q, AH3243Q, AH3280Q, AH3281Q, and AH3282Q are optimized to operate over a supply range of 2.7V to 27V. These features include a chopper-stabilized architecture and an internal bandgap regulator to provide temperature compensated supply for internal circuits. For robustness and protection, the device has built-in reverse blocking diode with a Zener clamp on the supply.

The built-in thermal protection also shuts down the chip if temperature rises to an abnormal value. This will automatically restart the chip once the junction temperature drops below the safe value.

For AH3241Q, AH3242Q, and AH3243Q 2-wire unipolar switches: when the flux density (south pole) exceeds B_{OP} , the supply current state is turned on (low or high). The output is held until a magnetic flux density falls below B_{RP} , causing output current to be turned off.

For AH3280Q, AH3281Q, and AH3282Q 2-wire latch switches: when the magnetic flux density is larger than B_{OP} , output current is turned on (high). The output state is held until a magnetic flux density reversal falls below B_{RP} , causing output current to be turned off (low).

Features and Performance

- Unipolar: AH3241Q, AH3242Q, AH3243Q
- Latch: AH3280Q, AH3281Q, AH3282Q
- Output Polarity:
 - Direct: AH3242Q, AH3243Q
 - Inverted: AH3241Q
- Wide Supply Voltage Operation: 2.7V to 27V
- Temperature Coefficient -1100ppm/°C (AH3242Q, AH3243Q)
- Chopper Stabilized Design Provides:
- Superior Temperature Stability
 - Minimal Switch Point Drift
 - Enhanced Immunity to Stress
- Battery polarity reverse connection protection
- Transient Spike Voltage Protection
- Over-Temperature Shut Down and Auto-Restart
- UVLO Protection
- High ESD Rating: HBM = 8kV, CDM = 1kV
- Ready for ISO 26262
- Temperature Range: -40°C to +150°C
- Totally Lead-Free & Fully RoHS Compliant (Notes 1, 2)
- Halogen- and Antimony-Free. "Green" Device (Note 3)
- The AH3241Q, AH3242Q, AH3243Q, AH3280Q, AH3281Q, and AH3282Q are suitable for automotive applications requiring specific change control; these parts are AEC-Q100 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and

- Lead-free
 - 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

Pin Assignments



SC59 (Type A1)





SIP-3 (Future Product)

Applications

- Position and Proximity Sensing in Automotive Applications
- Seat position
- Seatbelt buckle
- Wiper position
- Window lifter
- Gear selection position



Typical Applications Circuit



Notes: 4. The decoupling capacitor CIN between VDD and GND pins is needed for power stabilization and to strengthen the noise immunity; recommended capacitance is 100nF, as close to IC as possible.

Pin Descriptions

Package: SC59 and SIP-3 (Ammo Pack and Bulk Pack)

Pin Number	Pin Name	Function
1	V _{DD}	Supply voltage input
2	NC	No connection; can be connected to V _{DD} , GND, or left open.
3	GND	Ground



Functional Block Diagram



ADSOLUTE MAXIMUM RATINGS (Note 5) ($@I_A = +25^{\circ}C$, unless otherwise specified.)					
Symbol	Parameter	Rating	Unit		
V _{DD} (Note 6)	Supply Voltage	32	V		
V _{DDR} (Note 6)	Reverse supply voltage	-32	V		
В	Magnetic flux density	Unlimited	Gauss		
T _{J_MAX}	Maximum junction temperature	180	°C		
Ts	Storage Temperature	-55~180	°C		
ESD (HBM)	ESD (Human Body Model)	8000	V		
ESD (CDM)	ESD(Charged Device Model)	1000	V		

Absoluto Maximum Ratings (**- -**

5. Stresses greater than the "Absolute Maximum Ratings" specified above may cause permanent damage to the device. These are stress ratings only; Notes: functional operation of the device at these or any other conditions exceeding those indicated in this specification is not implied. Device reliability may be affected by exposure to absolute maximum rating conditions for extended periods of time.

6. Should not be exceeded the maximum junction temperature and maximum duration of 500ms.

Recommended Operating Conditions (@T_A = -40°C to +150°C, T_J = -40°C to +165°C unless otherwise specified.)

Symbol	Parameter	Min	Мах	Unit
V _{DD}	Supply Voltage, between V_{DD} and GND pins	2.7	27	V
T _{OP}	Operating Ambient Temperature	-40	150	°C





Symbol	Parameter	Conditions	Min	Тур	Max	Units
V _{DD}	Supply voltage (Note 8)	-	2.7	12	27	V
I _{OFF} (2)	Supply current off state	V _{DD} = 2.7 to 27 V (AH3280Q, AH3282Q)	2	3.3	5	mA
I _{OFF} (1)	Supply current off state	V _{DD} = 2.7 to 27 V (AH3241Q, AH3242Q, AH3243Q, AH3281Q)	5	6	6.9	mA
ION	Supply current on state	V _{DD} = 2.7 to 27 V	12	14.5	17	mA
V _{UVLO}	Under voltage lockout threshold	Voltage dropping	-	2.2	2.7	V
t _{UVLO}	Under-voltage lockout reaction time	-	-	10	-	μs
I _{DDR}	Reverse supply current	V _{DD} = -18V, T = -40°C to +150°C	-1.5	-	-	mA
T _{TP}	Thermal protection threshold	Junction temperature	-	190	-	°C
T _{TPR}	Thermal protection release threshold	Junction temperature	-	180	-	°C
FM	Maximum magnet switching frequency	$B > 3^*B_{OP}$, alternative square magnet field	30	50	-	kHz
Fc	Chopping frequency	-	-	1000	-	kHz
I _{SAFE}	Safe mode supply current	Safe mode supply current / Error Current (mA)	0.5	1	1.5	mA
TPON	Power on delay time (Note 9)	B > Bop+10GS	-	28	40	μs
TD	Response delay time (Note 10)	B > 3*B _{OP}	-	7	-	μs
T _{RF}	Current rise/fall time	V_{DD} = 12V, No bypass capacitor, C_{LOAD} = 50pF to GND	0.1	0.3	1	μs
POS	Power-Up State (Notes 9, 11)	t > T _{PON} (max), V _{DD} slew rate > 1V/µs	-	I _{OFF}	-	-
-	Output jitter	B≥3*B _{OPMAX} 1000 successive square wave switching under 1KHz	-	±3.3	-	μs

Notes: 7. Typical values are defined at TA = +25°C, VDD = 12V. Maximum and minimum values over the operating temperature range are not tested in production but guaranteed by design, process control and characterization. 8. VDD is the voltage between the VDD pin and the GND pin.

9. When power is initially turned on, V_{DD} must be operated in the correct voltage range to guarantee proper magnetic field sampling, output supply current state level is valid after the start up time of 28µs from V_{DD} higher than 2.7V. Guaranteed by design. 10. Time delayed from the magnetic threshold reached to the output rise or fall.

11. t > T_{PON} and $B_{RP} < B < B_{OP}$.



 $\label{eq:magnetic Characteristics} \mbox{ (Notes 12, 13) (T_A = -40^\circ C \mbox{ to } +150^\circ C, \mbox{ T_J = -40^\circ C \mbox{ to } +165^\circ C, \mbox{ V_{DD}= } 2.7 \mbox{ V to } 27 \mbox{ V, unless otherwise} \mbox{ otherwise} \mbox{ to } +165^\circ C, \mbox{ V_{DD}= } 2.7 \mbox{ V to } 27 \mbox{ V, unless otherwise} \mbox{ to } +165^\circ C, \mbox{ V_{DD}= } 2.7 \mbox{ to } 27 \mbox{ V, unless otherwise} \mbox{ to } +165^\circ C, \mbox{ V_{DD}= } 2.7 \mbox{ to } 27 \mbox{ V, unless otherwise} \mbox{ to } +165^\circ C, \mbox{ V_{DD}= } 2.7 \mbox{ to } 27 \mbox{ V, unless otherwise} \mbox{ to } +165^\circ C, \mbox{ V_{DD}= } 2.7 \mbox{ to } 27 \mbox{ V, unless otherwise} \mbox{ to } +165^\circ C, \mbox{ V_{DD}= } 2.7 \mbox{ to } 27 \mbox{ V, unless otherwise} \mbox{ to } +165^\circ C, \mbox{ V_{DD}= } 2.7 \mbox{ to } 27 \mbox{ V, unless otherwise} \mbox{ to } +165^\circ C, \mbox{ V_{DD}= } 2.7 \mbox{ to } 27 \mbox{ V, unless otherwise} \mbox{ to } +165^\circ C, \mbox{ V_{DD}= } 2.7 \mbox{ to } 27 \mbox{ V, unless otherwise} \mbox{ to } +165^\circ C, \mbox{ V_{DD}= } 2.7 \mbox{ to } 27 \mbox{ V, unless otherwise} \mbox{ to } +165^\circ C, \mbox{ V_{DD}= } 2.7 \mbox{ to } 27 \mbox{ V, unless otherwise} \mbox{ to } +165^\circ C, \mbox{ V_{DD}= } 2.7 \mbox{ to } 27 \mbox{$ specified)

Part Name	Test Condition	Operating Point B _{oP} (Gauss)		Release Point B _{RP} (Gauss)		Temperature Coefficient (ppm/°C)	I _{OFF} (mA)	Active Pole	Output Polarity		
		Min	Тур	Max	Min	Тур	Max	Тур	Тур		
41122440	T _A =25°C	65	90	120	45	70	100	0	6	Orauth	lassanta d
AH3241Q	T _A =-40~150°C	55	90	135	35	70	115	- 0	0	South	Inverted
41122420	T _A =25°C	40	60	80	20	40	60	1100	6	Orauth	Diment
AH3242Q	T _A =-40~150°C	30	60	90	10	40	70		0	South	Direct
AH2242O	T _A =25°C	27	45	63	10	28	46	1100	6	South	Direct
AH3243Q	T _A =-40~150°C	20	45	70	3	28	53	-1100			
AH33800	T _A =25°C	8	18	28	-28	-18	-8	0	3.3	South	Direct
A113200Q	T _A =-40~150°C	3	18	33	-33	-18	-3	0			
AU2291O	T _A =25°C	8	18	28	-28	-18	-8	0	6	Courth	Direct
AH3281Q	T _A =-40~150°C	3	18	33	-33	-18	-3	0	0	South	Direct
AH2282O	T _A =25°C	15	30	45	-45	-30	-15	0	2.2	3.3 South	Direct
AI 13202Q	T _A =-40~150°C	10	30	50	-50	-30	-10	0	5.5		





(SIP-3L)



2) Inverted South Pole Active

I_{OFF}

B+

Bop

12. Positive x-axis direction indicates the South Pole approaching the part marking surface of SIP3 and SC59 i.e. increasing south pole magnetic field Notes: strength to the sensor; reversing direction x-axis toward 0 means the decreasing south magnetic field strength to the sensor. Negative x-axis indicates north pole magnetic field to the part marking surface.

13. Typical values are defined at T_A = +25°C, V_{DD} = 12V. Maximum and minimum values over the operating temperature range is not tested in production but guaranteed by design, process control and characterization.



Typical Operating Characteristics



AH324XQ_AH328XQ Supply Current ON, IoN Performance

AH324XQ_AH3281Q Supply Current OFF, IOFF(1) Performance









TA = -40'C

TA = +25'C

TA =+150'C

28

Typical Operating Characteristics (cont.)



AH3241Q Magnetic Characteristics Performance



Release Point versus Temperature

18 20 22 24 26







Typical Operating Characteristics (cont.)



AH3242Q Magnetic Characteristics Performance

Release Point versus Temperature

-25 0 25 50 75 100 Ambient Temperature, T_A(°C)

10

-50

Release Point versus Supply voltage





125

150



Typical Operating Characteristics (cont.)



H3243Q Magnetic Characteristics Performance



Operation Point versus Supply voltage





Release Point versus Supply voltage



Switch Point Hysteresis versus Temperature Switch Point Hysteresis versus Supply voltage 35 35 Switch Point Hysteresis, BHY(G) Switch Point Hysteresis, B_{HY}(G) AH3243Q AH3243Q VDD=2.7V -TA = -40'C 30 30 -TA = +25'C VDD=12V -TA =+150'C VDD=27V 25 25 20 20 15 15 10 10 5 5 4 22 24 26 -50 -25 0 25 50 75 100 125 150 2 6 8 10 12 14 16 18 20 28 Supply Voltage, V_{DD} (V)

Ambient Temperature, T_A(℃)

AH3241Q, AH3242Q, AH3243Q

AH3280Q, AH3281Q, AH3282Q

Document number: DS41822 Rev. 1 - 2



Typical Operating Characteristics (continued)



AH3280Q_AH3281Q Magnetic Characteristics Performance



Release Point versus Temperature -30 VDD=2.7V AH3280Q AH3281Q VDD=12V -25 VDD=27V Release Point, BRP(G) -20 -15 -10 -5 0 -50 -25 25 100 150 0 50 75 125 Ambient Temperature, T_A(°C)

Release Point versus Supply voltage



Switch Point Hysteresis versus Temperature 60 -VDD=2.7V AH3280Q AH3281Q Switch Point Hysteresis, B_{HY}(G) 55 VDD=12V 50 VDD=27V 45 40 35 30 25 20 15 10 -50 -25 0 25 50 75 100 125 150 Ambient Temperature, T_A(°C)



Switch Point Hysteresis versus Supply voltage



Typical Operating Characteristics (cont.)



Operation Point versus Supply voltage 50 AH3282Q -TA =-40'C 45 Operation Point, Bop(G) TA = +25'C 40 TA =+150'C 35 30 25 20 15 2 4 6 8 10 12 14 16 18 20 22 24 26 28 Supply Voltage, V_{DD} (V)

Release Point versus Temperature



Release Point versus Supply voltage



Switch Point Hysteresis versus Temperature Switch Point Hysteresis versus Temperature 90 90 Switch Point Hysteresis, B_{HY}(G) Switch Point Hysteresis, B_{HY}(G) AH3282Q VDD=2.7V AH3282Q VDD=2.7V 80 80 VDD=12V VDD=12V VDD=27V VDD=27V 70 70 60 60 50 50 40 40 30 30 -50 -25 0 25 50 75 100 125 -50 -25 0 25 50 75 100 125 150 Ambient Temperature, T_A(℃) Ambient Temperature, T_A(℃)

AH3241Q, AH3242Q, AH3243Q AH3280Q, AH3281Q, AH3282Q Document number: DS41822 Rev. 1 - 2

150



Thermal Performance Characteristics

Symbol	Parameter	Conditions	Rating	Unit
R _{θ JA} P	Package Thermal Resistance	SC59, 50mm*50mm 2oz MRB PCB, single layer	268	°C/W
		SIP-3, 50mm*50mm 2oz MRB PCB, single layer	143	°C/W





Ordering Information



A: Ammo Box (Note 14) B: Bulk (Note 15)

	Baakaga		Bulk Box		7" Tape and Reel		Ammo Box	
Part Number	Code	Packaging	Quantity	Part Number Suffix	Quantity	Part Number Suffix	Quantity	Part Number Suffix
AH3241Q-P-A	Ρ	SIP-3 (Ammo Pack)	NA	NA	NA	NA	4000/Box	-A
AH3241Q-P-B	Ρ	SIP-3 (Bulk Pack)	1000	-В	NA	NA	NA	NA
AH3241Q-W-7	W	SC59 (Type A1)	NA	NA	3000/Tape & Reel	-7	NA	NA
AH3242Q-P-A	Р	SIP-3 (Ammo Pack)	NA	NA	NA	NA	4000/Box	-A
AH3242Q-P-B	Ρ	SIP-3 (Bulk Pack)	1000	-B	NA	NA	NA	NA
AH3242Q-W-7	W	SC59 (Type A1)	NA	NA	3000/Tape & Reel	-7	NA	NA
AH3243Q-P-A	Р	SIP-3 (Ammo Pack)	NA	NA	NA	NA	4000/Box	-A
AH3243Q-P-B	Р	SIP-3 (Bulk Pack)	1000	-В	NA	NA	NA	NA
AH3243Q-W-7	W	SC59 (Type A1)	NA	NA	3000/Tape & Reel	-7	NA	NA
AH3280Q-P-A	Ρ	SIP-3 (Ammo Pack)	NA	NA	NA	NA	4000/Box	-A
AH3280Q-P-B	Ρ	SIP-3 (Bulk Pack)	1000	-В	NA	NA	NA	NA
AH3280Q-W-7	W	SC59 (Type A1)	NA	NA	3000/Tape & Reel	-7	NA	NA
AH3281Q-P-A	Ρ	SIP-3 (Ammo Pack)	1000	-В	NA	NA	NA	NA
AH3281Q-P-B	Ρ	SIP-3 (Bulk Pack)	NA	NA	3000/Tape & Reel	-7	NA	NA
AH3281Q-W-7	W	SC59 (Type A1)	NA	NA	3000/Tape & Reel	-7	NA	NA
AH3282Q-P-A	Р	SIP-3 (Ammo Pack)	NA	NA	NA	NA	4000/Box	-A
AH3282Q-P-B	Р	SIP-3 (Bulk Pack)	1000	-В	NA	NA	NA	NA
AH3282Q-W-7	W	SC59 (Type A1)	NA	NA	3000/Tape & Reel	-7	NA	NA

14. Ammo Box is for SIP-3 (Ammo Pack) Spread Lead. Notes: 15. Bulk is for SIP-3 (Bulk Pack) Straight Lead.



Marking Information

(1) Package Type: SC59 (Type-A1)



Part Number	Package	Identification Code
AH3241Q	SC59 (Type A1)	BR
AH3242Q	SC59 (Type A1)	BS
AH3243Q	SC59 (Type A1)	BT
AH3280Q	SC59 (Type A1)	BW
AH3281Q	SC59 (Type A1)	BU
AH3282Q	SC59 (Type A1)	BV

(2) Package Type: SIP-3 (Ammo Pack), SIP-3 (Bulk Pack)



Part Number	Package	Identification Code
AH3241Q	SIP-3(Ammo Pack)	3241Q
AH3241Q	SIP-3 (Bulk Pack)	3241Q
AH3242Q	SIP-3(Ammo Pack)	3242Q
AH3242Q	SIP-3(Bulk Pack)	3242Q
AH3243Q	SIP-3(Ammo Pack)	3243Q
AH3243Q	SIP-3(Bulk Pack)	3243Q
AH3280Q	SIP-3(Ammo Pack)	3280Q
AH3280Q	SIP-3 (Bulk Pack)	3280Q
AH3281Q	SIP-3(Ammo Pack)	3281Q
AH3281Q	SIP-3 (Bulk Pack)	3281Q
AH3282Q	SIP-3 (Ammo Pack)	3282Q
AH3282Q	SIP-3 (Bulk Pack)	3282Q



Package Outline Dimensions (All dimensions in mm.)

Please see http://www.diodes.com/package-outlines.html for the latest version.

(1) Package Type: SC59 (Type A1)





	SC59 (Type A1)					
Dim	Min	Max	Тур			
Α		1.45				
A1	0.00	0.15				
A2	0.90	1.30	1.15			
b	0.30	0.50				
С	0.08	0.22	-			
D		2.90 B	SC			
Е		2.80 B	SC			
E1		1.60 B	SC			
е		0.95 B	SC			
e1		1.90 B	SC			
L	0.30	0.60	0.45			
L2		0.25 BSC				
θ1	5°	15°	10°			
All	Dimen	sions	in mm			

AH32xxQ Hall sensor





Package Outline Dimensions (Cont.) (All dimensions in mm.)

Please see http://www.diodes.com/package-outlines.html for the latest version.

(2) Package Type: SIP-3 (Bulk Pack)



SIP-3 (Bulk Pack)						
Dim	Min	Max	Тур			
Α	1.40	1.60	1.50			
b	0.33	0.43	0.38			
b2	0.40	0.508	0.46			
С	0.35	0.41	0.38			
D	3.90	4.30	4.10			
Е	2.80	3.20	3.00			
e1	1.24	1.30	1.27			
F	0.00	0.20				
J	2	.62 REF	-			
L	14.00	15.00	14.50			
L1	1.55	1.75	1.65			
S	0.63	0.84	0.74			
a1	_	_	5°			
a2	_	_	5°			
a3	_	_	45°			
a4	_		3°			
All [Dimensi	ons in	mm			

AH32xxQ SIP3 Hall sensor





Package Outline Dimensions (Cont.) (All dimensions in mm.)

Please see http://www.diodes.com/package-outlines.html for the latest version.

(3) Package Type: SIP-3 (Ammo Pack)



	SIP-3						
	(Ammo	Раск)	_				
Dim	Min	Max	Тур				
Α	1.40	1.60	1.50				
b	0.33	0.43	0.38				
b2a	0.40	0.52	0.46				
c	0.35	0.41	0.38				
D	3.90	4.30	4.10				
Е	2.80	3.20	3.00				
e1	1.24	1.30	1.27				
e2	2.40	2.90	2.65				
F	0.00	0.20	_				
ر	2	.62 REF	-				
L	14.00	15.00	14.50				
La	12.90	14.90	13.90				
L1	1.55	1.75	1.65				
L3	2.00	3.00	2.50				
s	0.63	0.84	0.74				
a1	_	_	5°				
a2			5°				
a3	_		45°				
a4	_		3°				
All C	Dimensi	ons in	mm				

AH32xxQ SIP3 Hall sensor





Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

(1) Package Type: SC59 (Type A1)



Dimensions	Value (in mm)
С	2.40
Х	0.80
X1	1.35
Y	1.00
Y1	3.40



IMPORTANT NOTICE

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes Incorporated.

LIFE SUPPORT

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

- A. Life support devices or systems are devices or systems which:
 - 1. are intended to implant into the body, or
 - 2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.
- B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2020, Diodes Incorporated

www.diodes.com